### SN54LS07, SN74LS07, SN74LS17 HEX BUFFERS/DRIVERS WITH OPEN-COLLECTOR HIGH-VOLTAGE OUTPUTS SDLS021A, D3517, MAY 1990-REVISED AUGUST 1991

- Converts TTL-Voltage Levels to MOS Levels
- High Sink-Current Capability
- Input Clamping Diodes Simplify System Design
- Open-Collector Driver for Indicator Lamps and Relays
- Package Options Include "Small Outline" Packages, Ceramic Chip Carriers, and Standard and Ceramic 300-mil DIPs

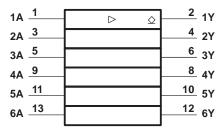
### description

These monolithic hex buffers/drivers feature high-voltage open-collector outputs to interface with high-level circuits or for driving high-current loads. They are also characterized for use as buffers for driving TTL inputs. The 'LS07 has a rated output voltage of 30 V and the 'LS17 has a rated output voltage of 15 V. The maximum sink current is 30 mA for the SN54LS07 and 40 mA for the SN74LS07 and SN74LS17.

These circuits are compatible with most TTL families. Inputs are diode-clamped to minimize transmission-line effects, which simplifies design. Typical power dissipation is 140 mW and average propagation delay time is 12 ns.

The SN54LS07 is characterized over the full military temperature range of -55°C to 125°C. The SN74LS07 and
SN74LS17 are characterized for operation from 0°C to 70°C.

## logic symbol<sup>†</sup>



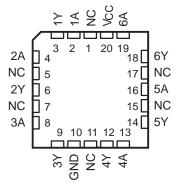
<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for D, J, and N packages.

#### SN54LS07 . . . J PACKAGE SN74LS07, SN74LS17 . . . D OR N PACKAGE (TOP VIEW)

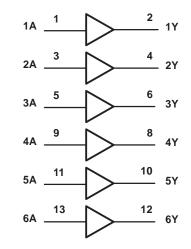
(101 11211)									
1		$\overline{\mathbf{t}}$		1					
1A[	1	$\cup$	14	] v <sub>cc</sub>					
1A[ 1Y[	2 3		13	] V <sub>CC</sub> ] 6A ] 6Y ] 5A ] 5Y					
2A [	3		12	]6Y					
2Y[	4		11	] 5A					
3A [	5		10	] 5Y					
3Y [	6		9	] 4A ] 4Y					
2A [ 2Y [ 3A [ 3Y [ GND [	7		8	4Y					
٦				Γ					

SN54LS07 ... FK PACKAGE (T0P VIEW)



NC - No internal connection

logic diagram (positive logic)



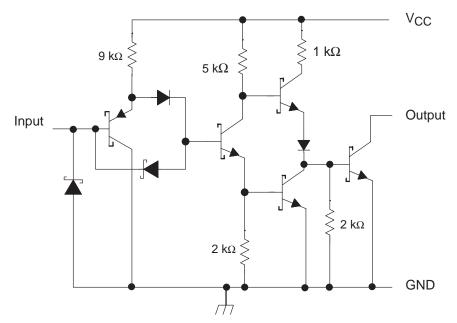
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# SN54LS07, SN74LS07, SN74LS17 HEX BUFFERS/DRIVERS WITH OPEN-COLLECTOR HIGH-VOLTAGE OUTPUTS

## schematic (each gate)



Resistor values shown are nominal.

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage, V <sub>CC</sub> Input voltage, V <sub>I</sub> (see Note 1)	
Output voltage, V <sub>O</sub> (see Notes 1 and 2): SN54LS07, SN74LS07	
SN74LS17	
Operating free-air temperature range: SN54LS07	–55°C to 125°C
SN54LS07, SN74LS17	0°C to 70°C
Storage temperature range	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. Voltage values are with respect to network ground terminal.

2. This is the maximum voltage that should be applied to any output when it is in the off state.

#### recommended operating conditions

			SN54LS07			SN74LS07 SN74LS17			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	
Vcc	Supply voltage		4.5	5	5.5	4.75	5	5.25	V
VIH	High-level input voltage		2			2			V
VIL	Low-level input voltage	input voltage			0.8			0.8	V
		'LS07			30			30	
VOH	High-level output voltage	'LS17						15	V
IOL	Low-level output current				30			40	mA
TA	Operating free-air temperature		-55		125	0		70	°C



# SN54LS07, SN74LS07, SN74LS17 **HEX BUFFERS/DRIVERS WITH OPEN-COLLECTOR HIGH-VOLTAGE OUTPUTS**

### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER TEST CONDITIONS <sup>†</sup>		ons†	SN54LS07			SN74LS07 SN74LS17			UNIT		
				MIN	TYP‡	MAX	MIN	TYP‡	MAX		
VIK	$V_{CC} = MIN,$	$I_{I} = -12 \text{ mA}$				-1.5			-1.5	V	
I <sub>OH</sub> V <sub>CC</sub> = MIN,	V <sub>IH</sub> = 2 V	'LS07, V <sub>OH</sub> = 30 V			0.25			0.25	mA		
	$v_{CC} = ivilla,$	∨IH = 2 ∨	'LS17, V <sub>OH</sub> = 15 V			0.25			0.25	mA	
V <sub>OL</sub> V <sub>CC</sub>			I <sub>OL</sub> = 16 mA			0.4			0.4	4 V	
	$V_{CC} = MIN, \qquad V$	V <sub>IL</sub> = 0.8 V	IOT = WAX§			0.7			0.7	v	
Ц	$V_{CC} = MAX,$	V <sub>I</sub> = 7 V				1			1	mA	
Ιн	$V_{CC} = MAX,$	VI = 2.4 V				20			20	μΑ	
١ <sub>IL</sub>	V <sub>CC</sub> = MAX,	V <sub>I</sub> = 0.4 V				-0.2			-0.2	mA	
Іссн	V <sub>CC</sub> = MAX					14			14	mA	
ICCL	V <sub>CC</sub> = MAX					45			45	mA	

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

<sup>‡</sup> All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C. § I<sub>OL</sub> = 30 mA for SN54 series parts and 40 mA for SN74 series parts.

# switching characteristics, $V_{CC} = 5 V$ , $T_A = 25^{\circ}C$ (see Note 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CO	MIN	ТҮР	МАХ	UNIT	
<sup>t</sup> PLH		V	D: 110.0	0. 45		6	10	
<sup>t</sup> PHL	A	Y	$R_{L} = 110 \Omega, \qquad C_{L} = 15 pF$			19	30	ns

NOTE 3: Load circuit and voltage waveforms are shown in Section 1 of TTL Logic Data Book, 1988.



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